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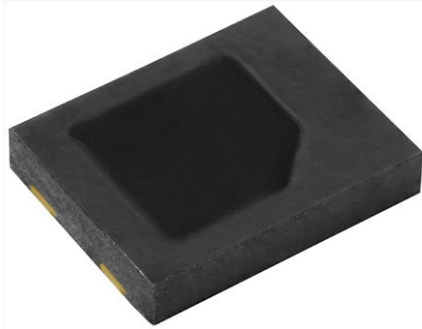
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Silicon PIN Photodiode



DESCRIPTION

VEMD5160X01 is a high speed and high sensitive PIN photodiode with a highly linear photoresponse. It is a low profile surface mount device (SMD) including the chip with a 7.5 mm² sensitive area and a daylight blocking filter matched with IR emitters operating at wavelength 850 nm or 890 nm.

FEATURES

- Package type: surface mount
- Package form: top view
- Dimensions (L x W x H in mm): 5 x 4 x 0.9
- Radiant sensitive area (in mm²): 7.5
- AEC-Q101 qualified
- Daylight blocking filter matched with 850 nm to 890 nm emitters
- High radiant sensitivity
- Excellent I_{ra} linearity
- Fast response times
- Angle of half sensitivity: $\varphi = \pm 65^\circ$
- Floor life: 72 h, MSL 4, according to J-STD-020
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

 AUTOMOTIVE
GRADE

RoHS
COMPLIANT
HALOGEN
FREE
GREEN
(5-2008)

APPLICATIONS

- High speed photo detector
- Small signal detection
- Proximity sensors

PRODUCT SUMMARY

| COMPONENT | I _{ra} (μA) | φ (deg) | λ _{0.1} (nm) |
|-------------|----------------------|---------|-----------------------|
| VEMD5160X01 | 26 | ± 65 | 700 to 1070 |

Note

- Test conditions see table “Basic Characteristics”

ORDERING INFORMATION

| ORDERING CODE | PACKAGING | REMARKS | PACKAGE FORM |
|------------------|---------------|------------------------------|--------------|
| VEMD5160X01 | Tape and reel | MOQ: 1000 pcs, 1000 pcs/reel | Top view |
| VEMD5160X01-GS15 | Tape and reel | MOQ: 5000 pcs, 5000 pcs/reel | Top view |

Note

- MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS (T_{amb} = 25 °C, unless otherwise specified)

| PARAMETER | TEST CONDITION | SYMBOL | VALUE | UNIT |
|---------------------------------------|---|--------------------|-------------|------|
| Reverse voltage | | V _R | 20 | V |
| Power dissipation | T _{amb} ≤ 25 °C | P _V | 240 | mW |
| Junction temperature | | T _j | 110 | °C |
| Operating temperature range | | T _{amb} | -40 to +110 | °C |
| Storage temperature range | | T _{stg} | -40 to +110 | °C |
| Soldering temperature | According to reflow solder profile fig. 8 | T _{sd} | 260 | °C |
| Thermal resistance junction / ambient | According to EIA / JESD51 | R _{thJA} | 350 | K/W |
| ESD safety HBM | ± 2000 V, 1.5 kΩ, 100 pF, 3 pulses | ESD _{HBM} | ≥ 2 | kV |

| BASIC CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified) | | | | | | |
|---|---|-----------------|------|-------------|------|---------------|
| PARAMETER | TEST CONDITION | SYMBOL | MIN. | TYP. | MAX. | UNIT |
| Forward voltage | $I_F = 50\text{ mA}$ | V_F | - | 0.8 | 1.0 | V |
| Breakdown voltage | $I_R = 100\text{ }\mu\text{A}$, $E = 0$ | $V_{(BR)}$ | 20 | - | - | V |
| Reverse dark current | $V_R = 10\text{ V}$, $E = 0$ | I_{ro} | - | 0.2 | 10 | nA |
| Diode capacitance | $V_R = 0\text{ V}$, $f = 1\text{ MHz}$, $E = 0$ | C_D | - | 80 | - | pF |
| | $V_R = 3\text{ V}$, $f = 1\text{ MHz}$, $E = 0$ | C_D | - | 35 | 40 | pF |
| Open circuit voltage | $E_e = 1\text{ mW/cm}^2$, $\lambda = 950\text{ nm}$ | V_o | - | 350 | - | mV |
| Temperature coefficient of V_o | $E_e = 1\text{ mW/cm}^2$, $\lambda = 950\text{ nm}$ | TK_{V_o} | - | -2.6 | - | mV/K |
| Short circuit current | $E_e = 1\text{ mW/cm}^2$, $\lambda = 950\text{ nm}$ | I_k | - | 26 | - | μA |
| Temperature coefficient of I_k | $E_e = 1\text{ mW/cm}^2$, $\lambda = 835\text{ nm}$ | TK_{I_k} | - | 0.1 | - | %/K |
| Reverse light current | $E_e = 1\text{ mW/cm}^2$, $\lambda = 950\text{ nm}$, $V_R = 5\text{ V}$ | I_{ra} | 20 | 26 | 31 | μA |
| | $E_e = 1\text{ mW/cm}^2$, $\lambda = 890\text{ nm}$, $V_R = 5\text{ V}$ | I_{ra} | - | 38 | - | μA |
| Angle of half sensitivity | | ϕ | - | ± 65 | - | deg |
| Wavelength of peak sensitivity | | λ_p | - | 840 | - | nm |
| Range of spectral bandwidth | | $\lambda_{0.1}$ | - | 700 to 1070 | - | nm |
| Rise time | $V_R = 5\text{ V}$, $R_L = 50\text{ }\Omega$, $\lambda = 820\text{ nm}$ | t_r | - | 30 | - | ns |
| Fall time | $V_R = 5\text{ V}$, $R_L = 50\text{ }\Omega$, $\lambda = 820\text{ nm}$ | t_f | - | 30 | - | ns |

BASIC CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)

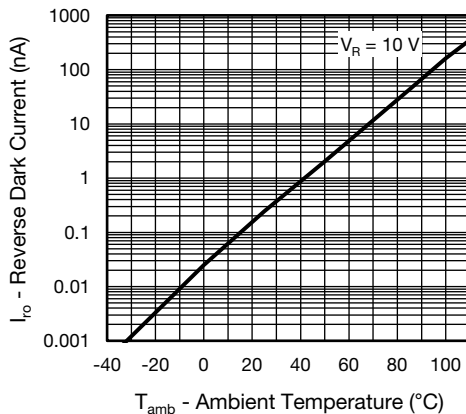
 Basic characteristics graphs to be extended to $110\text{ }^{\circ}\text{C}$ ambient temperatures where applicable.


Fig. 1 - Reverse Dark Current vs. Ambient Temperature

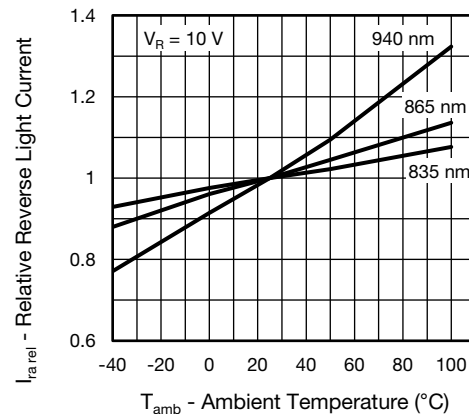


Fig. 2 - Relative Reverse Light Current vs. Ambient Temperature

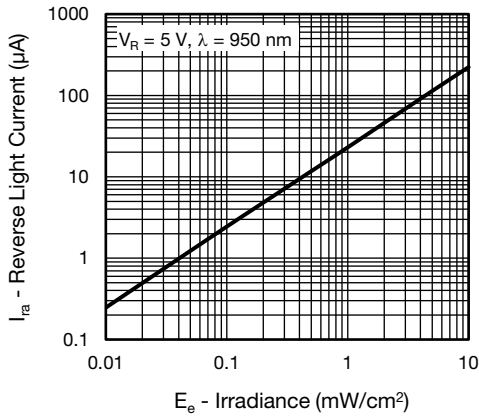


Fig. 3 - Reverse Light Current vs. Irradiance

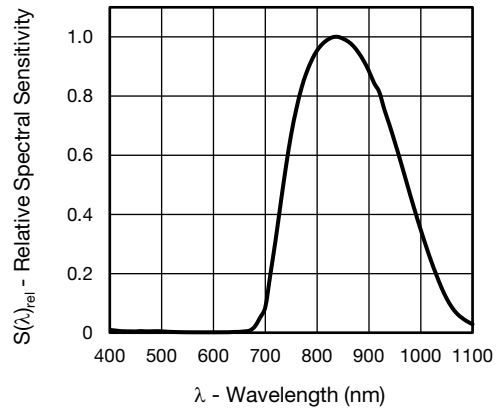


Fig. 6 - Relative Spectral Sensitivity vs. Wavelength

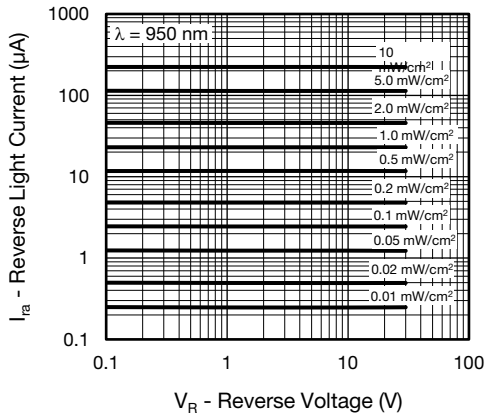


Fig. 4 - Reverse Light Current vs. Reverse Voltage

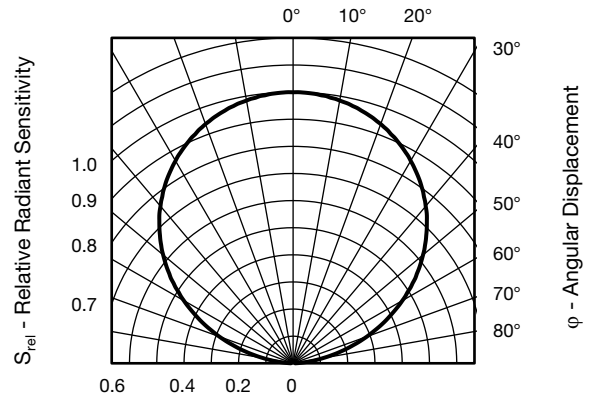


Fig. 7 - Relative Radiant Sensitivity vs. Angular Displacement

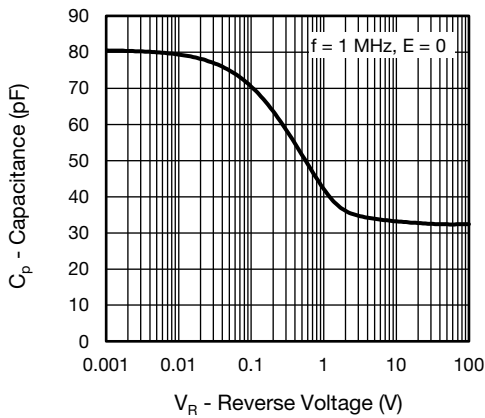
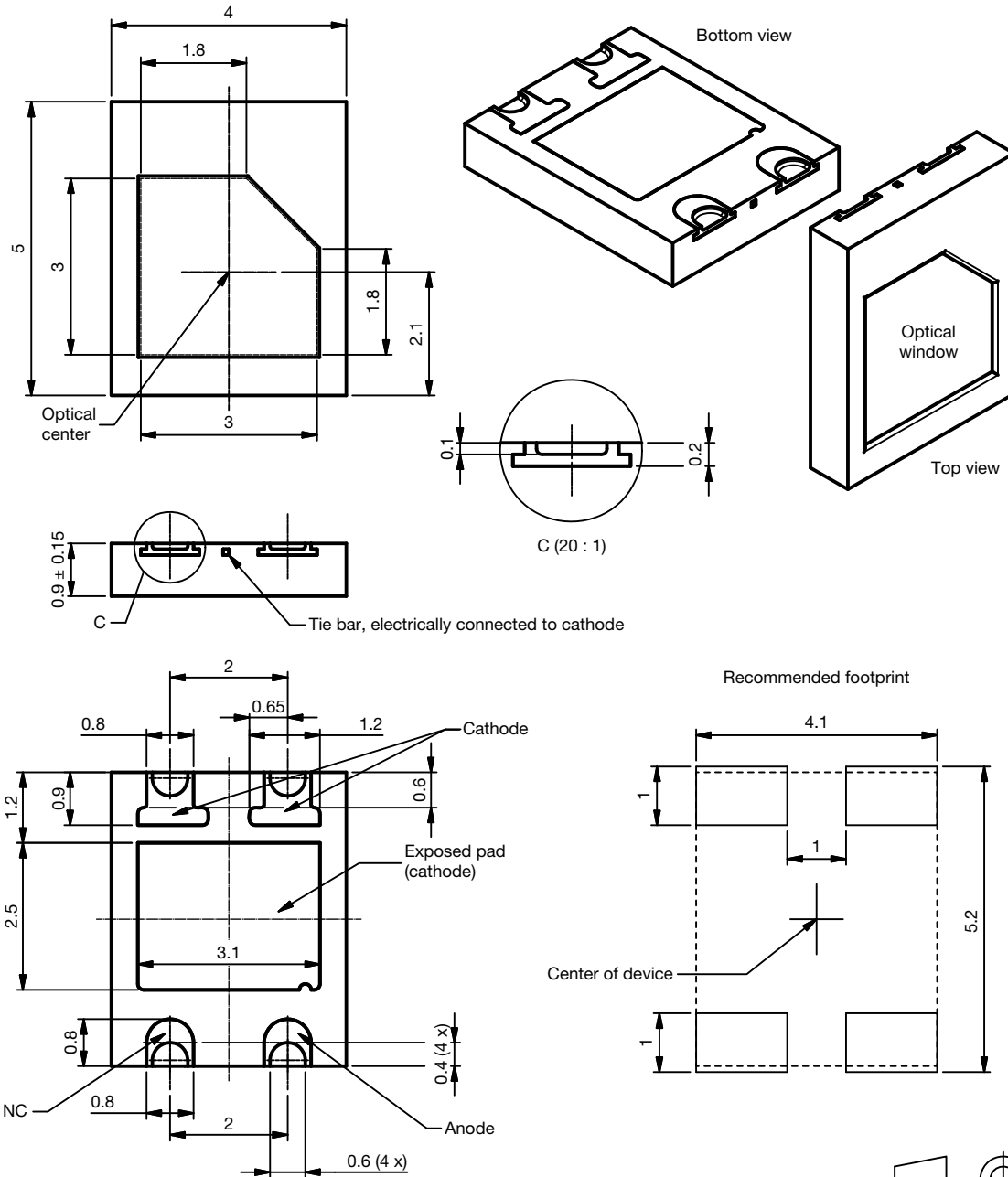


Fig. 5 - Diode Capacitance vs. Reverse Voltage

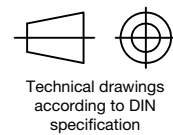


PACKAGE DIMENSIONS in millimeters



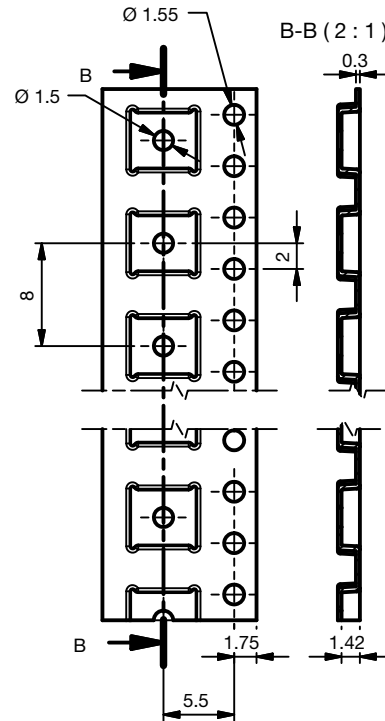
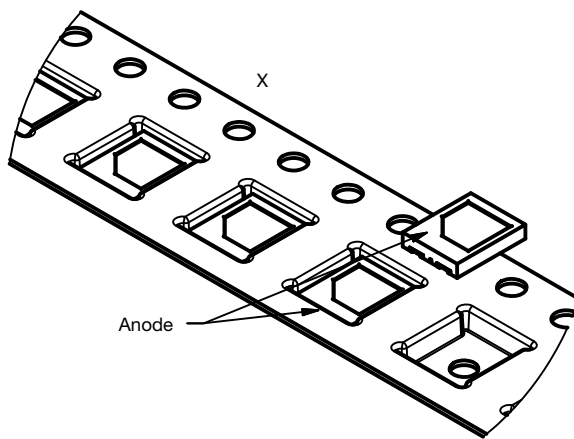
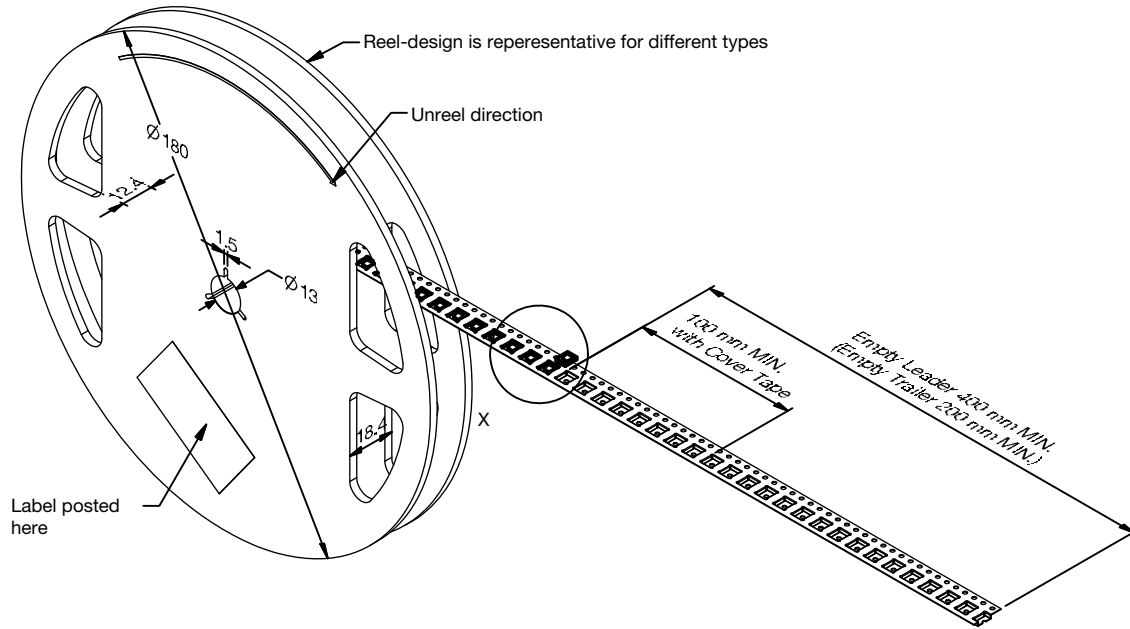
Drawing- No.: 6.550-5329.01-4
Issue: 2; 03.03.2016

Not indicated tolerances ± 0.1





TAPE AND REEL DIMENSIONS in millimeters



Drawing-No.: 9.800-5129.01-4;
Issue: 1; 20.07.2015

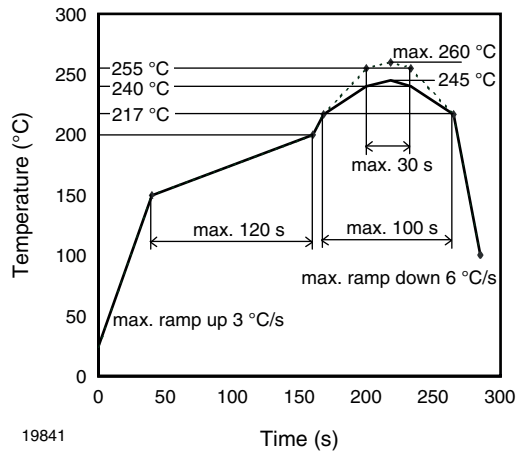
SOLDER PROFILE


Fig. 8 - Lead (Pb)-free Reflow Solder Profile
According to J-STD-020D

DRYPACK

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

FLOOR LIFE

Time between soldering and removing from MBB must not exceed the time indicated in J-STD-020:

Moisture sensitivity: level 4

Floor life: 72 h

Conditions: $T_{amb} < 30\text{ °C}$, $RH < 60\%$

DRYING

In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-020 or recommended conditions:

192 h at $40\text{ °C} (+ 5\text{ °C})$, $RH < 5\%$

or

96 h at $60\text{ °C} (+ 5\text{ °C})$, $RH < 5\%$.



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